NPN Triple Diffused Planar Silicon Transistor

2SC4635



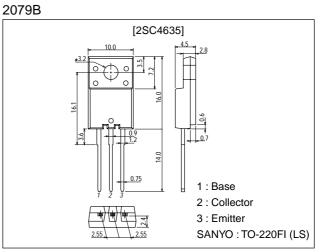
1500V/20mA High-Voltage Amplifier, High-Voltage Switching Applications

Features

- · High breakdown voltage (V_{CEO} min=1500V).
- · Small Cob (typical Cob=1.9pF).
- · Full-isolation package.
- · High reliability (Adoption of HVP process).

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		1500	V
Collector-to-Emitter Voltage	VCEO		1500	V
Emitter-to-Base Voltage	V _{EBO}		5	V
Collector Current	ι _C		20	mA
Collector Current (Pulse)	ICP		60	mA
Collector Dissipation	PC		2	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

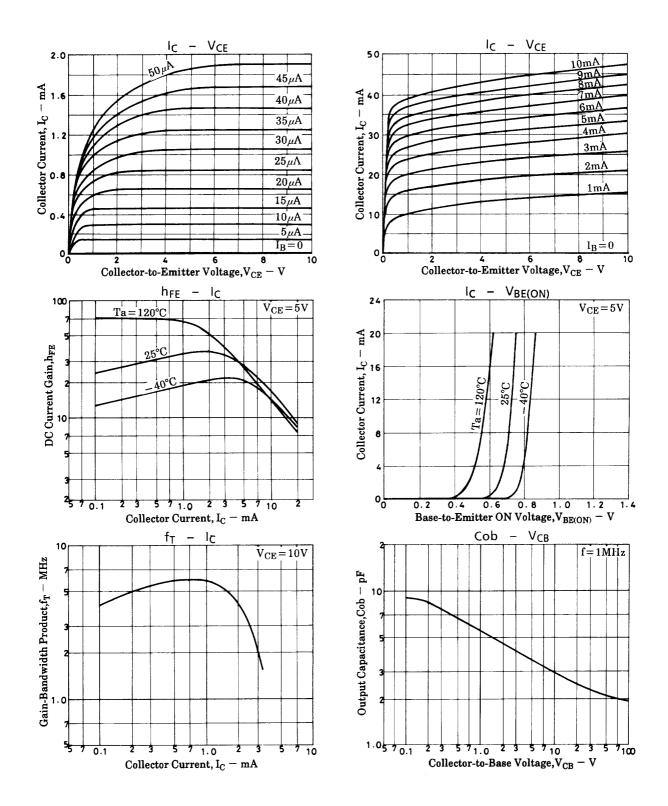
Electrical Characteristics at Ta = 25°C

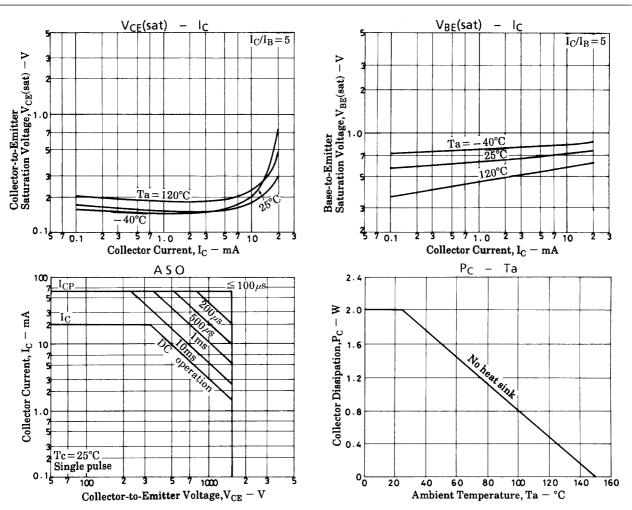
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Collector Cutoff Current	I _{CBO}	V _{CB} =1500V, I _E =0			1	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0			1	μΑ
DC Current Gain	hFE	V _{CE} =5V, I _C =600µA	10		60	
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =600µA		6		MHz
Collector-to-Emitter Saturation Voltage	VCE(sat)	I _C =1.5mA, I _B =0.3mA			5	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =1.5mA, I _B =0.3mA			2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =100μA, I _E =0	1500			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	1500			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =100μA, I _C =0	5			V

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onin
Output Capacitance	Cob	V _{CB} =100V, f=1MHz		1.9		pF
Thermal Resistance	Rthj-c	Junction – case			8.3	°C/W





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